

Computation of dendritic microstructures using a level set method

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We compute time-dependent solutions of the sharp-interface model of dendritic solidification in two dimensions by using a level set method. The steady-state results are in agreement with solvability theory. Solutions obtained from the level set algorithm are compared with dendritic growth simulations performed using a phase-field model and the two methods are found to give equivalent results. Furthermore, we perform simulations with unequal diffusivities in the solid and liquid phases and find reasonable agreement with the available theory.

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Various numerical approaches [1–4] have been developed to solve the difficult moving boundary problem that governs the growth of dendrites [5–7]. Unfortunately, the direct solution of the time-dependent Stefan problem is troublesome and usually requires front tracking and lattice deformation in order to compute the moving solid-liquid interface, which is often very complicated topologically. In general, the methods developed to tackle the free-boundary problem have difficulty in handling topology changes, such as the merging and breaking of surfaces, and are usually not easily extendable to higher dimensions.

In order to avoid the difficulties associated with tracking a sharp interface, the phase-field model of solidification has been developed and is currently the most popular technique for simulating dendritic growth. The phase-field model avoids the computational difficulties associated with front tracking by introducing an auxiliary order parameter, or phase-field, $\psi(\mathbf{r}, t)$ that couples to the evolution of the thermal field. The dynamics of $\psi(\mathbf{r}, t)$ are designed to follow the evolving solidification front [8–11], which is defined by the zero level set $\psi(\mathbf{r}, t) = 0$. Because the interface is never explicitly tracked, complicated topology changes are handled easily. Furthermore, the extension of the phase-field model to higher dimensions is straightforward.

Although phase-field models have been very useful in studying solidification patterns, there are still some limitations in this approach. The proper use of these models requires that an asymptotic analysis be performed in order to obtain a mapping between the parameters of the phase-field equations and the sharp-interface equations [12–14]. The asymptotics involve expanding the phase-field equations in some small parameter proportional to the interface width, W , and as a result, the phase-field model only reproduces the dynamics of the sharp-interface equations in the limit where the expansion parameter is sufficiently small. Computationally, the grid spacing must be small enough to resolve the interfacial region, which is on the order of W . This restriction is generally not a problem for the symmetric model of solidification (where the diffusivities in the solid and liquid phases are assumed to be the same) because it is possible to

have W on the order of the capillary length [14]. However, phase-field asymptotics for unequal diffusivities lead to computationally inconvenient forms because correction terms that are inconsistent with the sharp-interface equations are generated by the unequal diffusivities and nonmonotonic behavior of the phase-field is required in the interfacial region, which requires extra grid resolution and hence slower computational performance [15]. The generalization of the phase-field approach to handle discontinuous material properties requires a better understanding of the mapping between the phase-field model and the sharp-interface formulation in order to avoid problems with properly resolving the interface.

The level set method is a computational approach that has the capability of avoiding the above mentioned limitations of front tracking methods and phase-field models. This method, first introduced by Osher and Sethian [16], is conceptually similar to a phase-field model in that the solid-liquid interface is represented as the zero contour of a level set function, $\phi(\mathbf{r}, t)$, which has its own equation of motion. The movement of the interface is taken care of implicitly through an advection equation for $\phi(\mathbf{r}, t)$. Thus, topology changes and the extension of the method to higher dimensions can be handled in a straightforward manner. Unlike the phase-field model, there is no arbitrary interface width introduced in the level set method; the sharp-interface equations can be solved directly and, as a result, no asymptotics are required. Discontinuous material properties can also be dealt with in a simple manner.

The level set method has been applied to several problems involving moving boundaries [17–19], including solidification. Prior work on dendritic growth includes an application of the method to a boundary integral formulation [20] as well as the direct solution of the sharp-interface equations [21]. While these simulations have reproduced the qualitative features of dendrites, as well as some quantitatively accurate solutions to exactly soluble problems, some of the simulations of anisotropic dendritic growth were not necessarily converged [21]. Furthermore, the results were not compared with theoretical predictions of dendritic growth.

In this article, we demonstrate that the level set method can be used to solve the free-boundary problem for solidification to calculate quantitatively accurate solutions for dendritic growth. We present results from simulations in two dimensions and show that the solutions converge to the steady-state predicted by microscopic solvability theory. Time-dependent results are also compared with calculations using a phase-field model and good agreement is found for all times. Furthermore, we perform simulations with unequal diffusivities (a case which is not yet possible with phase-field models) and find that the prediction of Barbieri and Langer [22] provides a fair quantitative fit to our results.

The solidification of a pure substance is described by a free-boundary problem for the temperature in the solid and liquid phases, and the position of the interface between them:

$$\partial_t u = D \nabla^2 u, \quad (1)$$

$$V_n = (D \partial_n u)_{\text{Solid}} - (D \partial_n u)_{\text{Liquid}}, \quad (2)$$

$$u_i = -d(\theta) \kappa - \beta(\theta) V_n. \quad (3)$$

The temperature T has been rescaled as a dimensionless thermal field $u = (T - T_m)/(L/C_p)$, where T_m , L , and C_p represent the melting temperature, the latent heat of fusion, and the specific heat at constant pressure, respectively. The thermal diffusivity, D , can be different in the solid and liquid phases. Equation (2) describes energy conservation at the solid-liquid interface, where V_n is the local outward normal interface velocity and ∂_n refers to the outward normal derivative at the interface. Finally, Eq. (3) is known as the Gibbs–Thomson condition and describes the deviation of the interface temperature, u_i , from equilibrium due to the local curvature, κ , and interface kinetics. $d(\theta) = \gamma(\theta) T_m C_p / L^2$ is the anisotropic capillary length, proportional to the surface tension $\gamma(\theta)$, and $\beta(\theta)$ is the anisotropic kinetic coefficient. Here we assume that $\beta(\theta) = 0$ and that the capillary length has the form $d(\theta) = d_0(1 - 15\epsilon \cos 4\theta)$, where ϵ is the anisotropy strength and θ is the angle between the local normal vector at the interface, \vec{n} , and the x -axis.

We solve the above free-boundary problem by using a level set algorithm, which involves the following steps: (i) advancing the interface, (ii) reinitializing the level set function to be a signed distance function, and (iii) solving for the new thermal field. The general level set method is described below. We wish to note that in our simulations we implement a *localized* level set method, described in detail in Ref. [23], in which calculations of ϕ are performed only in a narrow region around the interface. We have not yet made an attempt to make our algorithm more computationally efficient by using adaptive mesh refinement.

(i) *Advancing the interface.* The level set function is defined as the signed normal distance from the solid–liquid interface such that ϕ is positive in the liquid phase, negative in the solid phase, and zero at the interface. ϕ satisfies the pure advection equation

$$\frac{\partial \phi}{\partial t} + F |\nabla \phi| = 0. \quad (4)$$

Integrating Eq. (4) for one time step results in moving the contours of ϕ along the directions normal to the interface according to the velocity field F , which varies in space. F is constructed to be an extension of the interface velocity, V_n , such that $F = V_n$ for points on the interface and the lines of constant F are normal to the interface. Thus, advecting ϕ according to Eq. (4) moves the front with the correct velocity.

Rather than using a partial differential equation to generate F (as in Refs. [21,23]), we construct F in the following manner: ϕ represents the normal distance from the solidification front, so the value of ϕ at each gridpoint on the computational lattice can be used to locate a particular point on the interface. If \vec{x}_g is the location of the gridpoint, the associated point on the interface is at $\vec{x}_i = \vec{x}_g - \phi \vec{n}$, where the normal vector $\vec{n} = \nabla \phi / |\nabla \phi|$. The temperature at \vec{x}_i is then calculated by using Eq. (3); θ is easily found from \vec{n} , and the curvature, $\kappa = \nabla \cdot \vec{n}$, is interpolated at \vec{x}_i from values of κ at neighboring gridpoints. \vec{n} and κ are calculated using standard, centered finite difference approximations to the partial derivatives of ϕ . Next, values of u are interpolated in both the liquid and solid phases, a distance Δx (the size of the grid spacing) away from \vec{x}_i along the normal direction. These two interpolated temperatures are used along with u_i to approximate the difference in the normal derivative of u at \vec{x}_i and thus find V_n [Eq. (3)]. Because \vec{x}_i and \vec{x}_g lie in the same line normal to the interface, the value of F at \vec{x}_g is simply V_n . The field F can be determined at all gridpoints in this way.

After F is known, the interface can be advanced one time step. For stability, we discretize Eq. (4) using a fifth-order WENO (weighted essentially nonoscillatory) scheme in space and a third-order Runge-Kutta scheme in time [24]. However, the overall accuracy of our algorithm is second-order in space and first-order in time.

(ii) *Reinitialization.* After solving Eq. (4) for one time step, the level set function will no longer be equal to the distance away from the interface. It is necessary to *reinitialize* ϕ to be a signed distance function. This step is accomplished by solving

$$\frac{\partial \phi}{\partial t} + S(\phi) [|\nabla \phi| - 1] = 0, \quad (5)$$

to steady state. $S(\phi)$ takes on the value $+1$ in the liquid phase, -1 in the solid phase, and is zero at the interface. We typically iterate Eq. (5) three times in order to obtain an accurate distance function. Like Eq. (4), this equation is discretized using a fifth-order WENO scheme in space and a third-order Runge-Kutta scheme in time [24].

(iii) *Solving for the new thermal field.* The thermal field is updated by solving Eq. (1) using a modified Crank-Nicolson scheme. Different diffusivities in the two phases can be taken into account by simply noting the sign of the level set function and using the appropriate diffusion coefficient in the finite difference stencil. Special care has to be taken for gridpoints near the interface. If $|\phi| \leq \Delta x$, the level set function is used to determine whether the front intersects the stencil and, if so, interpolate where the interface crosses the stencil. The

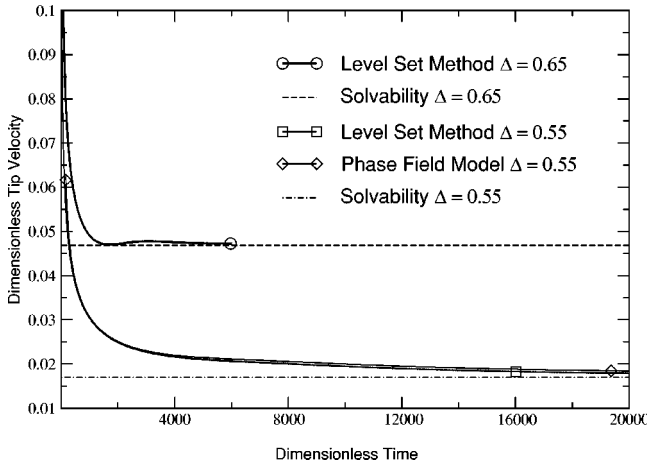


FIG. 1. Time evolution of the dimensionless tip velocity for simulations at $\Delta = 0.65$ and 0.55 .

stencil is then modified to take into account the location of the interface and the Gibbs-Thomson condition.

We compute four-fold symmetric dendrites in an $L \times L$ square box using the procedure described above. Solidification is initiated by a small quarter disk of radius R_0 in the lower left-hand corner of the box. The initial level set function is $\phi(x, y) = \sqrt{x^2 + y^2} - R_0$, where x and y are the usual Cartesian coordinates. The initial temperature is $u = 0$ in the solid and decays exponentially away from the interface to $u = -\Delta$ as $\vec{x} \rightarrow \infty$, where the far-field undercooling is $\Delta = (T_m - T_\infty)/(L/C_p)$ and T_∞ is the temperature far ahead of the solidification front in the liquid.

Equations (1)–(3) have been studied extensively to determine the steady-state features of dendritic growth [6,7]. According to microscopic solvability theory, these equations admit a family of discrete solutions. Only the fastest growing of this set of solutions is stable. This solution is the dynamically selected “operating state” for the dendrite and corresponds to a unique tip shape and velocity. Recent calculations of dendritic growth using phase-field models have been found to be in good agreement with the predictions of microscopic solvability theory [14,25]. We observe similar agreement with the use of the level set algorithm and obtain results that are within a few percent of theoretical predictions. Figure 1 shows the dimensionless tip velocity of the dendrite, $\tilde{V}_{\text{tip}} = V_{\text{tip}}d_0/D$, vs dimensionless time, $\tilde{t} = tD/d_0^2$, for computations at undercoolings of $\Delta = 0.65$ and 0.55 . For all of these simulations $D = 1$, $d_0 = 0.5$, $\beta = 0$, $R_0 = 15$, and $\epsilon = 0.05$. For the $\Delta = 0.65$ simulation, $L = 200$, $\Delta x = 0.2$, and the time step is chosen to be $\Delta t = 0.002$. For the $\Delta = 0.55$ simulation, $L = 800$, $\Delta x = 0.4$, and $\Delta t = 0.008$. To ensure grid convergence, Δx and Δt were refined until the steady-state tip velocity did not vary by more than 2%.

We also compare our level set results with simulations of dendritic growth performed using a phase-field model. Although calculations using phase-field models have been compared with a steady-state theory, there have been no comparisons made between time-dependent phase-field calculations and time-dependent solutions of the sharp-interface equations for multidimensional dendritic growth. The phase-field model calculations presented here were performed using a special adaptive mesh algorithm, as described in Ref. [25].

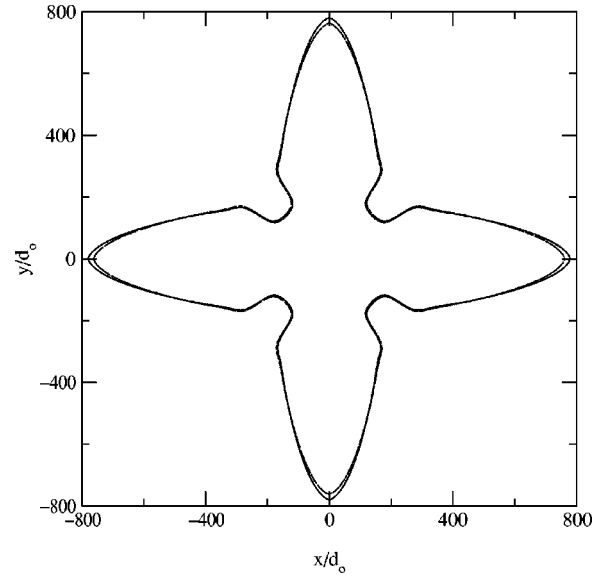


FIG. 2. Comparison of dendritic shapes computed from the level set method and phase-field model for $\Delta = 0.55$, shown at $\tilde{t} = 37\,600$.

The tip velocity data from the phase-field model and level set method at $\Delta = 0.55$ are in excellent agreement with each other (within 3%), as shown in Fig. 1. Similar agreement is found in the dendritic shapes for these simulations, presented at $\tilde{t} = 37\,600$ in Fig. 2. These comparative results, combined with the recent demonstration of the equivalence of various phase-field models [26], provide an excellent foundation for the validity of the phase-field approach in simulating solidification microstructures.

The results presented here so far have used $D_S = D_L$, where D_S and D_L are the diffusivities in the solid and liquid phases, respectively. With our level set algorithm, we can also investigate the more general case where the diffusivities are unequal. We performed additional simulations at $\Delta = 0.65$ with $D_S = 0.75, 0.5, 0.25$, and 0 while keeping $D_L = 1$. The only available benchmark for the case of nonsymmetric

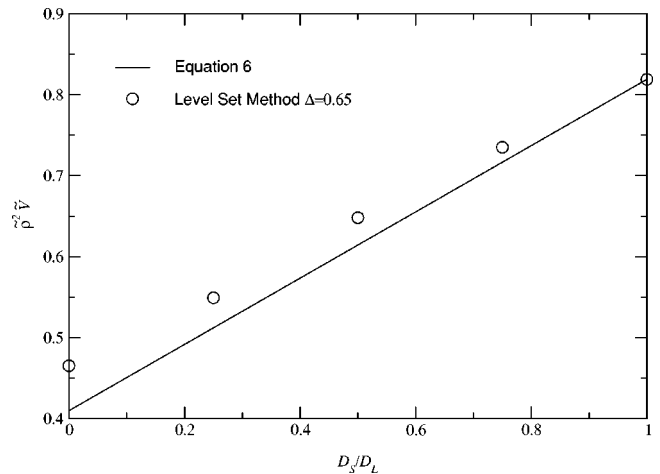


FIG. 3. $\bar{\rho}^2 \bar{V}$ for different values of D_S/D_L . The circles are data from level set simulations at $\Delta = 0.65$. The solid line is the theoretical prediction of Barbieri and Langer fitted to the data point at $D_S/D_L = 1$.

diffusion is the linearized solvability theory of Barbieri and Langer [22], which predicts

$$\tilde{\rho}^2 \tilde{V} \approx \frac{1 + D_S/D_L}{2} (\tilde{\rho}^2 \tilde{V})_{D_S/D_L=1}, \quad (6)$$

where $\tilde{\rho} = \rho/d_0$ and $\tilde{V} = Vd_0/D$ are the steady-state dimensionless tip radius and velocity, respectively. The values of $\tilde{\rho}^2 \tilde{V}$ obtained from the level set simulations are compared with Eq. (6) in Fig. 3. The fit is surprisingly good (an error of about 13% at $D_S/D_L=0$), considering Eq. (6) was obtained from a linearized theory in the limit of small undercoolings.

In conclusion, the level set method should be considered as a viable alternative to the use of phase-field models. We have used a level set algorithm that can produce accurate calculations of dendritic growth which can be compared favorably with solvability theory as well as time-dependent phase-field model simulations. The level set method can also

handle discontinuous material properties easily, which is currently very difficult with the phase-field approach. However, we should note that our implementation is not at all efficient. The practical application of this method to more realistic systems will require some sort of adaptive technique. In the future, we would like to use more computationally efficient implementations of this algorithm and apply these methods to problems in directional solidification, where the ability to simulate unequal diffusivities is of great interest.

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